

**SECTION 2. FORMS PTO/SB/08A and 08B (formerly Form PTO-1449)**

**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

Applicants: Susan A. Alie, et al. Attorney Docket: 2550/177  
 Serial No: ~~na~~ 10/737,231 Art Group Unit: ~~na~~ 2815  
 Date Filed: 12/15/2003 Examiner Name: ~~Not yet assigned~~ Jasmine elank  
 Invention: Semiconductor Assembly With Conductive Rim And Method Of Producing The Same

**LIST OF PATENTS AND PUBLICATIONS FOR  
 APPLICANT'S INFORMATION DISCLOSURE STATEMENT**

U.S. PATENT DOCUMENTS					
Examiner Initials	Reference Number	Document Number	Issue Date	Inventor	Class/Subclass
Jbe	AA	US 5,355,022	10/11/1994	Kazuyuki Sugahara, et al.	257/768
	AB	US 5,939,633	08/17/1999	Michael W. Judy	73/514.32
	AC	US 6,505,511 B1	01/14/2003	John A. Geen	73/504.12
	AD	US 6,448,109 B1	09/10/2002	Marice S. Karpman	438/108
	AE	US 5,545,912	08/13/1996	Ljubisa Ristic, et al.	257/417
	AF	US 6,323,550 B1	11/27/2001	John R. Martin, et al.	257/704
Jbe	AG	US 6,118,181	09/12/2000	Paul P. Merchant, et al.	257/757

Examiner Signature: Jasmine

Date Considered: 7/15/05

EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; draw line through citation *if not* in conformance and not considered. Include copy of this form with next communication to applicant.



## SECTION 2. FORMS PTO/SB/08A and 08B (formerly Form PTO-1449)

## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicants: Alie et al.

Attorney Docket: 2550/177

Serial No: 10/737,231

Art Group Unit: ~~2814~~ 2815

Date Filed: December 15, 2003

Examiner Name: J. Clark

Invention: SEMICONDUCTOR ASSEMBLY WITH CONDUCTIVE RIM AND METHOD OF PRODUCING THE SAME

LIST OF PATENTS AND PUBLICATIONS FOR  
APPLICANT'S SUPPLEMENTAL INFORMATION DISCLOSURE STATEMENT

U.S. PATENT DOCUMENTS					
Examiner Initials	Reference Number	Document Number	Issue Date	Inventor	Class/Subclass
Jbe	AH	US 5,929,497	July 27, 1999	Chavan et al.	257/417

FOREIGN PATENT DOCUMENTS						
Examiner Initials	Reference Number	Country Code	Document Number	Publication Date	Patentee or Applicant	Class/Subclass
Jbe	AI	EP	1219565 A1	July 3, 2002	STMicroelectronics	B81C 3/00
	AJ	EP	1296374 A1	March 26, 2003	STMicroelectronics Hewlett Packard Company	H01L 23/48
	AK	WO	02/093122 A2	Nov. 21, 2002	Robert Bosch GMBH	G01L 9/00
Jbe	AL	WO	01/56921 A2	Aug. 9, 2001	Raytheon Company	B81B 7/00

OTHER DOCUMENTS			
Examiner Initials	Reference Number	Author	Title of Article, Title of Journal, Volume Number, Page Numbers, Date
Jbe	AM	Authorized Officer Katrin Sommermeyer	<i>International Search Report</i> , International Searching Authority, March 14, 2005, 7 pages.
	AN	Chavan et al.	<i>A Monolithic Fully-Integrated Vacuum-Sealed CMOS Pressure Sensor</i> , 2000 IEEE, Document No. 0-7803-5273-4/00, 341-346, 6 pages.
Jbe	AO	Wolffenbuttel	<i>Low-temperature intermediate Au-Si wafer bonding; eutectic or silicide bond</i> , Sensors and Actuators A 62, 1997, 680-686, 7 pages.

Examiner Signature:

Jasmine Clark

Date Considered:

07/15/05

EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; draw line through citation *if not* in conformance and not considered. Include copy of this form with next communication to applicant.